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A journal at the forefront of the design and understanding of solid-state and crystalline materials

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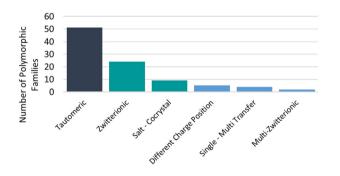
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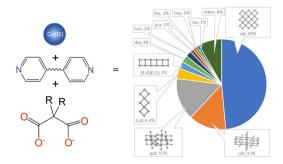
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Amy Woods-Ryan, Cheryl L. Doherty and Aurora J. Cruz-Cabeza*



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A journal at the forefront of the design and understanding of solid-state and crystalline materials

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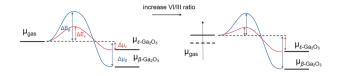


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Metal-organic chemical vapor deposition of ε-Ga₂O₃ thin film using N₂O as a precursor

Shujian Chen, Zimin Chen,* Weiqu Chen, Zeyuan Fei, Tiecheng Luo, Jun Liang, Xinzhong Wang, Gang Wang and Yanli Pei*



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Preparation of large-size single-crystal metalorganic frameworks via the Marangoni effect

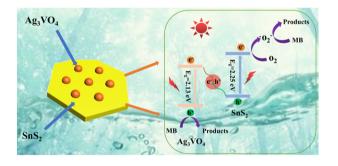
Fuqiang Fan,* Zhihui Zhang, Jin Guo, Liying Zhang, Xuemin Zhang, Tiegiang Wang and Yu Fu*



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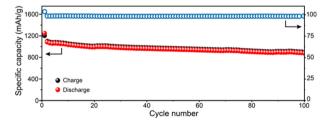
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Qiang Li,* Shiwu He, Lijie Wang, Jupu Song, Jiapeng Wang, Chunfeng Shao, Zhenfei Tian and Yi Liu*



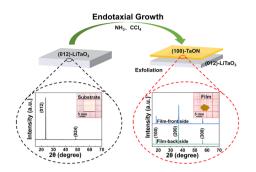
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Chengyao Zhu, Jin Wang, Guiying Xu, Xuan Du, Chuxin Chen, Xiangwei Yang, Chongjun Bao and Guo Gao*



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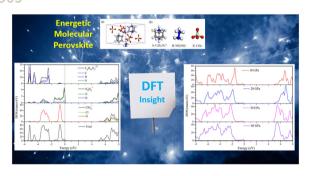
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Growth mechanism of [100]-oriented TaON film through an endotaxial transformation from a (012)-LiTaO₃ single crystal substrate

Xuesen Qin, Huiliang Li, Zeyan Wang,* Zhaoke Zheng, Peng Wang, Hefeng Cheng, Yuanyuan Liu, Yuchen Fan, Ying Dai and Baibiao Huang*

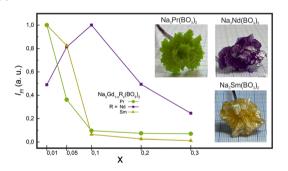
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Effects of hydrostatic pressure on structural, mechanical, and electronic properties of energetic molecular perovskite (C₆H₁₄N₂)(NH₂NH₃)(ClO₄)₃: a **DFT-D** insight

Qiaoli Li, Shenshen Li and Jijun Xiao*

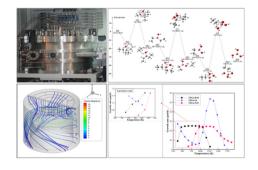
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Growth and characterization of $Na_3R(BO_3)_2$ (R = La-Gd) borates: crystal structure, high-temperature behavior, and optical properties

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Quantum chemical calculation and growth process of Ga₂O₃ grown via TEGa under different oxygen sources in MOCVD

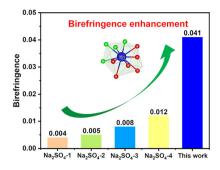
Jie Wang, Tie-cheng Luo, Zhuo Yang, Yi-cong He, Jian Li and Gang Wang*

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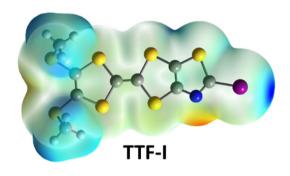
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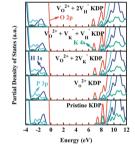
Haia Kharraz, Hadi Hachem, Yann Le Gal, Thierry Roisnel, Olivier Jeannin, Frédéric Barrière, Thierry Guizouarn and Dominique Lorcy*

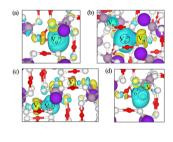


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Structural and electronic properties and optical absorption of oxygen vacancy cluster defects in KDP crystals: hybrid density functional theory investigation

Yang Li, Guokai Hao, Jianyu Bai, Tingting Sui, Liening Wei, Xun Sun, Xian Zhao, Mingxia Xu and Baoan Liu*

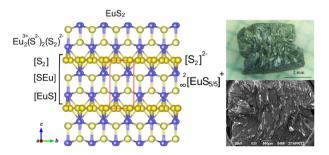




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Structural, optical and transport properties of layered europium disulfide synthesized under high pressure

E. A. Ekimov, S. N. Nikolaev, A. G. Ivanova, V. A. Sidorov, A. A. Shiryaev, I. I. Usmanov, A. L. Vasiliev, V. V. Artemov, M. V. Kondrin,* M. A. Chernopitsskiy and V. S. Krivobok



CORRECTION

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Correction: High-pressure and low-temperature structural study of claudetite I, a monoclinic layered As₂O₃ polymorph

Piotr A. Guńka,* Michael Hanfland, Yu-Sheng Chen and Janusz Zachara